

# Silicon, SPDT Switch, Nonreflective, 100 MHz to 13 GHz

## **Data Sheet**

### FEATURES

Nonreflective 50 Ω design Low insertion loss: 0.8 dB at 8 GHz High isolation: 45 dB at 8 GHz High input linearity P1dB: 39 dBm IP3: 60 dBm typical High power handling 35 dBm insertion loss path 27 dBm hot switching ESD rating: 2 kV (Class 2) HBM No low frequency spurious 0.05 dB RF settling time: 375 ns 0.1 dB RF settling time: 300 ns 16-lead, 3 mm × 3 mm LFCSP Pin-compatible with HMC1118, low frequency cutoff version

### **APPLICATIONS**

**Test instrumentation** 

Microwave radios and very small aperture terminals (VSATs) Military radios, radars, and electronic counter measures (ECMs) Fiber optics and broadband telecommunications

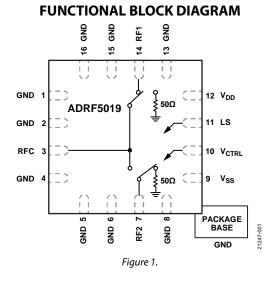
### **GENERAL DESCRIPTION**

The ADRF5019 is a nonreflective, single pole, double throw (SPDT) RF switch manufactured in a silicon process.

The ADRF5019 operates from 100 MHz to 13 GHz with better than 0.8 dB insertion loss and 45 dB of isolation at 8 GHz. The ADRF5019 has a nonreflective design, and the RF ports are internally terminated to 50  $\Omega$ .

The ADRF5019 switch requires a dual supply voltage of +3.3 V and -2.5 V and positive control voltage inputs. This switch employs complementary metal-oxide semiconductor (CMOS)-compatible and low voltage transistor transistor logic (LVTTL)-compatible controls.

# **ADRF5019**



The ADRF5019 can also operate with a single positive supply voltage ( $V_{DD}$ ) applied. The negative supply voltage ( $V_{SS}$ ) is tied to ground. Even in single-supply operation mode, the ADRF5019 can cover the 100 MHz to 13 GHz operating frequency and maintain good power handling performance. See the Applications Information section for more details.

The ADRF5019 is pin-compatible with the HMC1118, the low frequency cutoff version, which operates from 9 kHz to 13.0 GHz.

The ADRF5019 comes in a 16-lead, lead frame chip scale package (LFCSP) and operates from  $-40^{\circ}$ C to  $+105^{\circ}$ C.

Rev. 0

### **Document Feedback**

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106, U.S.A. Tel: 781.329.4700 ©2019 Analog Devices, Inc. All rights reserved. Technical Support www.analog.com

# TABLE OF CONTENTS

Features	l
Applications	L
Functional Block Diagram	L
General Description	L
Revision History	2
Specifications	3
Electrical Specifications	3
Absolute Maximum Ratings	5
Thermal Resistance	5
Power Derating Curves	5
ESD Caution	5
Pin Configuration and Function Descriptions	5
Interface Schematics	5

# Typical Performance Characterics .7 Insertion Loss, Return Loss, and Isolation .7 Input Compression and Input Third-Order Intercept .8 Theory of Operation 10 RF Input and Output 10 Power Supply. 10 Applications Information 11 Layout Considerations 11 Board Layout 11 Outline Dimensions 12 Ordering Guide 12

### **REVISION HISTORY**

8/2019—Revision 0: Initial Version

# SPECIFICATIONS ELECTRICAL SPECIFICATIONS

 $V_{\text{DD}}$  = 3.3 V,  $V_{\text{SS}}$  = -2.5 V, LS = 3.3 V,  $V_{\text{CTRL}}$  = 0 V or 3.3 V, and  $T_{\text{CASE}}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted.

Table 1.

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
FREQUENCY RANGE	f		100		13,000	MHz
INSERTION LOSS	IL					
Between RFC and RF1 or RFC and RF2 (On)		100 MHz to 3 GHz		0.6		dB
		100 MHz to 8 GHz		0.8		dB
		100 MHz to 10 GHz		1.0		dB
		100 MHz to 13 GHz		1.5		dB
RETURN LOSS	RL					
Between RFC and RF1 or RFC and RF2 (On)		100 MHz to 3 GHz		26		dB
		100 MHz to 8 GHz		22		dB
		100 MHz to 13 GHz		9		dB
RF1 or RF2 (Off)		100 MHz to 3 GHz		26		dB
		100 MHz to 8 GHz		14		dB
		100 MHz to 13 GHz		5		dB
ISOLATION				5		4.5
Between RFC and RF1 or RCF and RF2 (Off)		100 MHz to 3 GHz		50		dB
		100 MHz to 8 GHz		45		dB
		100 MHz to 10 GHz		35		dB
		100 MHz to 13 GHz		25		dB
SWITCHING CHARACTERISTICS				23		ub
Dual Supply		$V_{DD} = 3.3 V, V_{SS} = -2.5 V$				
Rise Time and Fall Time	t <sub>RISE</sub> , t <sub>FALL</sub>	10% to 90% of RF output		35		ns
On Time and Off Time		50% of triggered digital control input voltage		150		
On time and On time	ton, toff	$(V_{CTL})$ to 90% of RF output		150		ns
RF Settling Time						
0.1 dB		50% of triggered $V_{CTL}$ to 0.1 dB of final RF output		300		ns
0.05 dB		50% of triggered $V_{CTL}$ to 0.05 dB of final RF output		375		ns
Single Supply		$V_{DD} = 3.3 V, V_{SS} = 0 V$				
Rise Time and Fall Time	trise, t <sub>FALL</sub>	10% to 90% of RF output		180		ns
On Time and Off Time	ton, toff	50% of triggered $V_{CTL}$ to 90% of RF output		285		ns
INPUT LINEARITY <sup>1</sup>		100 MHz to 13 GHz				
Dual Supply		$V_{DD} = 3.3 \text{ V}, V_{SS} = -2.5 \text{ V}$				
Input Compression						
0.1 dB	P0.1dB			38		dBm
1 dB	P1dB			39		dBm
Intermodulation Distortion						
Input Third-Order Intercept	IIP3	Two tone input power = 12 dBm each tone, $\Delta f = 1 MHz$		60		dBm
Single Supply		$V_{DD} = 3.3 V, V_{SS} = 0 V$				
Input Compression						
0.1 dB	P0.1dB			25		dBm
1 dB	P1dB			28		dBm
Intermodulation Distortion						
Input Third-Order Intercept	IIP3	Two tone input power = 12 dBm each tone, $\Delta f = 1 MHz$		55		dBm
SUPPLY CURRENT	<u> </u>	V <sub>DD</sub> pin and V <sub>ss</sub> pin				
Positive Supply Current	IDD	55 F		20		μΑ
Negative Supply Current	Iss			0.5		μΑ

# **ADRF5019**

Parameter	Symbol	Test Conditions/Comments	Min	Тур	Max	Unit
DIGITAL CONTROL INPUTS		V <sub>CTRL</sub> pin and LS pin				
Voltage						
Low	VINL		0		0.8	v
High	VINH		2		3.3	V
Current						
Low and High Current	I <sub>INL</sub> , I <sub>INH</sub>			<1		μΑ
RECOMMENDED OPERATING CONDITONS						
Supply Voltage						
Positive	V <sub>DD</sub>		3.0		3.6	V
Negative	Vss		-2.75		-2.25	V
Digital Control Input Voltage	VCTL		0		V <sub>DD</sub>	V
RF Input Power, Dual Supply <sup>2</sup>	PIN	$V_{DD} = 3.3 V$ , $V_{SS} = -2.5 V$ , $f = 2 GHz$ , $T_{CASE} = 85^{\circ}C^{3}$				
Insertion Loss Path		RF signal is applied to RFC or through connected RF1 or RF2			35	dBm
Isolation Path		RF signal is applied to the terminated RF1 or RF2			27	dBm
Hot Switching		RF signal is present at RFC while switching between RF1 and RF2			27	dBm
RF Input Power, Single Supply <sup>2</sup>	P <sub>IN</sub>	$V_{DD} = 3.3 \text{ V}, V_{SS} = 0 \text{ V}, f = 2 \text{ GHz}, T_{CASE} = 85^{\circ}\text{C}^{3}$				
Insertion Loss Path		RF signal is applied to RFC or through connected RF1 or RF2			27	dBm
Isolation Path		RF signal is applied to the terminated RF1 or RF2			22	dBm
Hot Switching		RF signal is present at RFC while switching between RF1 and RF2			22	dBm
Case Temperature	TCASE		-40		+105	°C

<sup>1</sup> For input linearity performance vs. frequency, see Figure 13 to Figure 20. <sup>2</sup> For power derating vs. frequency, see Figure 2 and Figure 3. Power derating is applicable for insertion loss path, terminated path, and hot switching power specifications. <sup>3</sup> For operation at 105°C, the power handling degrades from the  $T_{CASE} = 85^{\circ}C$  specification by 3 dB.

# **ABSOLUTE MAXIMUM RATINGS**

### Table 2.

Rating
–0.3 V to +3.7 V
–2.8 V to +0.3 V
$-0.3$ V to $V_{\text{DD}}$ + 0.3 V
3 mA
37 dBm
28 dBm
30 dBm
28 dBm
23 dBm
23 dBm
23 dBm
135°C
−65°C to +150°C
260°C
2 kV (Class 2)

<sup>1</sup> For power derating vs. frequency, see Figure 2 and Figure 3. Power derating is applicable for insertion loss path, terminated path, and hot switching power specifications.

 $^2$  For operation at 105°C, the power handling degrades from the  $T_{\text{CASE}}$  = 85°C specification by 3 dB.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

### THERMAL RESISTANCE

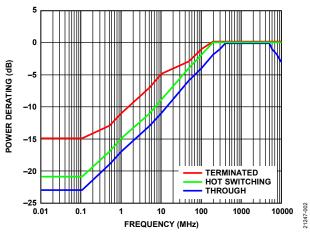
Thermal resistance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

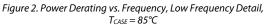
 $\theta_{\rm JC}$  is the junction to case bottom (channel to package bottom) thermal resistance.

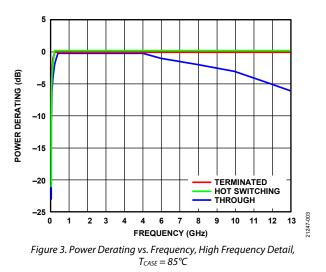
### Table 3. Thermal Resistance

Package Type	οις	Unit
CP-16-38		
Through Path	106	°C/W
Terminated Path	100	°C/W

### **POWER DERATING CURVES**







### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# **PIN CONFIGURATION AND FUNCTION DESCRIPTIONS**

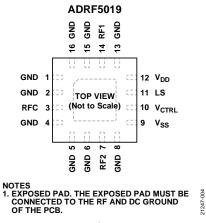


Figure 4. Pin Configuration (Top View)

### **Table 4. Pin Function Descriptions**

Pin No.	Mnemonic	Description
1, 2, 4 to 6, 8, 13, 15, 16	GND	Ground. These pins must be connected to the RF and dc ground of the PCB.
3	RFC	RF Common Port. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 5 for the interface schematic.
7	RF2	RF Throw Port 2. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 5 for the interface schematic.
9	Vss	Negative Supply Voltage Pin. See Figure 8 for the interface schematic.
10	VCTRL	Control Input Pin. See Figure 6 for interface schematic. See Table 5 for the truth table.
11	LS	Logic Select Input Pin. See Figure 6 for the interface schematic. See Table 5 for the truth table.
12	V <sub>DD</sub>	Positive Supply Voltage Pin. See Figure 7 for the interface schematic.
14	RF1	RF Throw Port 1. This pin is dc-coupled to 0 V and ac matched to 50 $\Omega$ . No dc blocking capacitor is required when the RF line potential is equal to 0 V dc. See Figure 5 for the interface schematic.
	EPAD	Exposed Pad. The exposed pad must be connected to the RF and dc ground of the PCB.

### **INTERFACE SCHEMATICS**

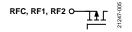


Figure 5. RFC, RF1, and RF2 Pin Interface Schematic

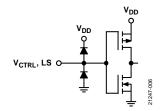


Figure 6. Digital Pins Interface Schematic

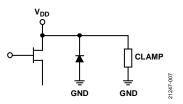


Figure 7. V<sub>DD</sub> Pin Interface Schematic

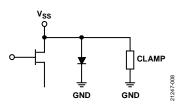


Figure 8. Vss Pin Interface Schematic

# TYPICAL PERFORMANCE CHARACTERICS INSERTION LOSS, RETURN LOSS, AND ISOLATION

 $V_{DD}$  = 3.3 V,  $V_{SS}$  = -2.5 V,  $V_{CTRL}$  and LS = 0 V or  $V_{DD}$ , and  $T_{CASE}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted.

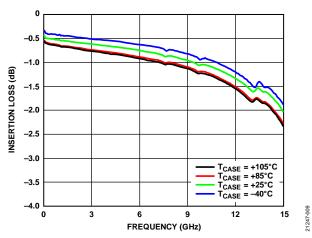


Figure 9. Insertion Loss vs. Frequency over Temperature

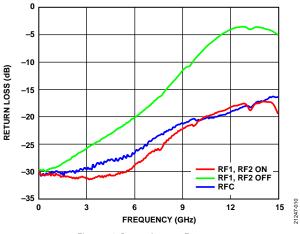


Figure 10. Return Loss vs. Frequency

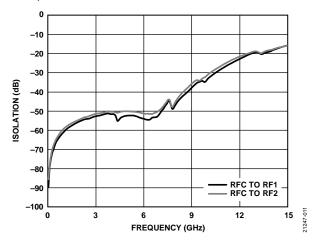


Figure 11. Isolation Between RFC and RFx Ports vs. Frequency

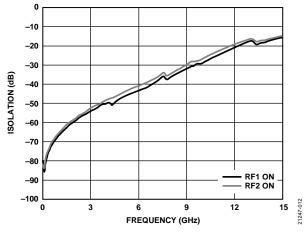


Figure 12. Isolation Between RF1 and RF2 Ports vs. Frequency

# **ADRF5019**

### INPUT COMPRESSION AND INPUT THIRD-ORDER INTERCEPT

 $V_{DD}$  = 3.3 V,  $V_{CTRL}$  and LS = 0 V or  $V_{DD}$ , and  $T_{CASE}$  = 25°C in a 50  $\Omega$  system, unless otherwise noted. All of the large signal performance parameters are measured on the ADRF5019-EVALZ evaluation board.

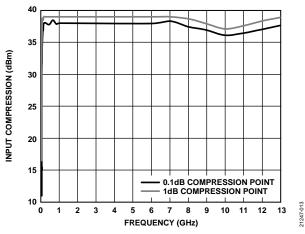


Figure 13. P0.1dB and P1dB Input Compression vs. Frequency,  $V_{ss} = -2.5 V$ 

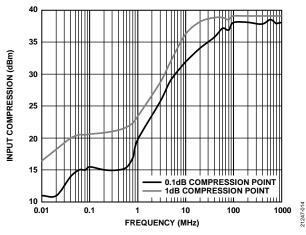


Figure 14. P0.1dB and P1dB Input Compression vs. Frequency (Low Frequency Detail),  $V_{SS} = -2.5 V$ 

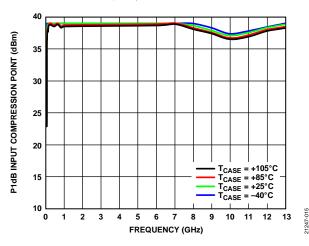


Figure 15. P1dB Input Compression Point vs. Frequency over Temperature,  $V_{SS} = -2.5 V$ 

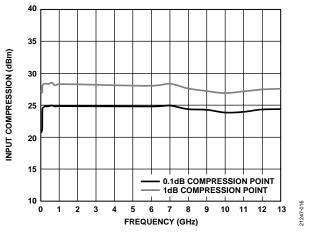


Figure 16. P0.1dB and P1dB Input Compression vs. Frequency,  $V_{SS} = 0 V$ 

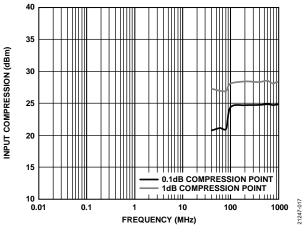


Figure 17. P0.1dB and P1dB Input Compression vs. Frequency (Low Frequency Detail),  $V_{SS} = 0 V$ 

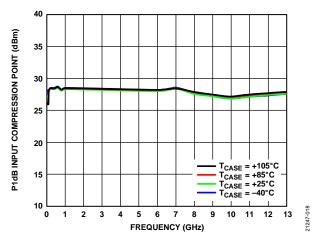


Figure 18. P1dB Input Compression Point vs. Frequency over Temperature (Low Frequency Detail),  $V_{SS} = 0 V$ 

# **Data Sheet**

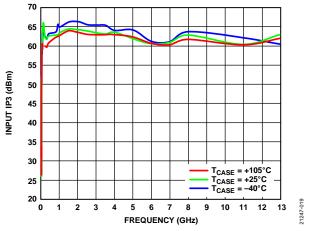


Figure 19. Input IP3 vs. Frequency over Temperature,  $V_{SS} = -2.5 V$ 

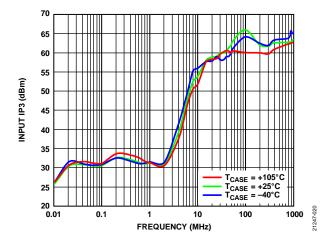


Figure 20. Input IP3 vs. Frequency over Temperature (Low Frequency Detail),  $V_{\rm SS} = -2.5 \ V$ 

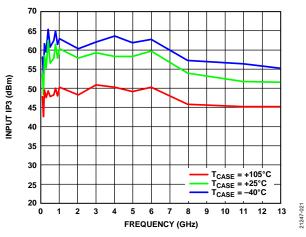


Figure 21. Input IP3 vs. Frequency over Temperature,  $V_{SS} = 0 V$ 

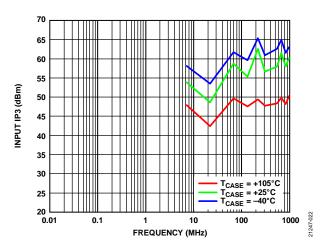


Figure 22. Input IP3 vs. Frequency over Temperature (Low Frequency Detail),  $V_{\rm SS} = 0 V$ 

# **ADRF5019**

# THEORY OF OPERATION

The ADRF5019 integrates a driver to perform logic functions internally and to provide the user with the advantage of a simplified positive voltage control interface. The driver features two digital control input pins ( $V_{CTRL}$  and LS) that control the state of the RF paths, determining which RF port is in the insertion loss state and which path is in the isolation state (see Table 5).

### **RF INPUT AND OUTPUT**

The RF ports (RFC, RF1, and RF2) are dc-coupled to 0 V, and no dc blocking is required at the RF ports when the RF line potential is equal to 0 V.

The RF ports are internally matched to 50  $\Omega$ . Therefore, external matching networks are not required.

The ADRF5019 is bidirectional with equal power handling capabilities. An RF input signal ( $RF_{IN}$ ) can be applied to the RFC port or to the RF1 port or the RF2 port.

The insertion loss path conducts the RF signal between the selected RF throw port and the RF common port. The isolation path provides high loss between the insertion loss path and the unselected RF throw port, which is nonreflective, by using an internal 50  $\Omega$  termination resistor.

### **POWER SUPPLY**

The ADRF5019 requires a positive supply voltage applied to the  $V_{\text{DD}}$  pin and a negative supply voltage applied to the  $V_{\text{SS}}$  pin. Bypassing capacitors are recommended on the supply lines to filter high frequency noise.

The ideal power-up sequence is as follows:

- 1. Connect to GND.
- 2. Power up the  $V_{DD}$  and  $V_{SS}$  voltages. Power up  $V_{SS}$  after  $V_{DD}$  to avoid current transients on  $V_{DD}$  during ramp up.
- 3. Power up the digital control inputs. The order of the digital control inputs is not important. However, powering the digital control inputs before the  $V_{DD}$  voltage supply can inadvertantly forward bias and damage the internal ESD protection structures. To avoid this damage, use a series 1 k $\Omega$  resistor to limit the current flowing into the control pin. Use pull-up or pull-down resistors if the controller output is in a high impedance state after the  $V_{DD}$  voltage is powered up and the control pins are not driven to a valid logic state.
- 4. Apply an RF input signal to RFC, RF1, or RF2.

The ideal power-down sequence is the reverse order of the power-up sequence.

### Single-Supply Operation

The ADRF5019 can operate with a single positive supply voltage applied to the  $V_{DD}$  pin and  $V_{SS}$  pin connected to ground. However, some performance degradations can occur in the input compression and input third-order intercept.

Digital Control Inputs			RF Paths
LS	VCTRL	RF1 to RFC	RF2 to RFC
High	Low	Insertion loss (on)	Isolation (off)
High	High	Isolation (off)	Insertion loss (on)
Low	Low	Isolation (off)	Insertion loss (on)
Low	High	Insertion loss (on)	Isolation (off)

### Table 5. Control Voltage Truth Table

# APPLICATIONS INFORMATION LAYOUT CONSIDERATIONS

All measurements in this data sheet are measured on the ADRF5019-EVALZ evaluation board. The design of the ADRF5019-EVALZ board serves as a layout recommendation for ADRF5019 application.

See the ADRF5019-EVALZ user guide for more information on using the evaluation board.

### **BOARD LAYOUT**

The ADRF5019-EVALZ is a 4-layer board. The outer copper (Cu) layers are 0.7 mil to 2.2 mil plated and are separated by dielectric materials. Figure 23 shows the ADRF5019-EVALZ board stack up.

The board layout and stackup shown in Figure 23 are used to make the measurements included in this data sheet.

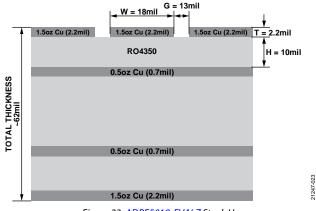


Figure 23. ADRF5019-EVALZ Stack Up

All RF and dc traces are routed on the top copper layer. The inner and bottom layers are ground planes that provide a solid ground for the RF transmission lines. The top dielectric material (H) is 10 mil Rogers RO4350, which allows optimal RF performance. The middle and bottom dielectric layers provide mechanical strength. The overall evaluation board thickness is approximately 62 mil, which allows Subminiature Version A (SMA) connectors to be connected at the board edges.

### **RF AND DIGITAL CONTROLS**

The RF transmission lines use a coplanar waveguide (CPWG) model with a width of 18 mil and a ground spacing (G) of 13 mil and have a characteristic impedance of 50  $\Omega$ . For optimal RF and thermal grounding, as many plated through vias as possible are arranged around the transmission lines and under the exposed pad of the package.

The RF input and output ports (RFC, RF1, and RF2) are connected through 50  $\Omega$  transmission lines to the SMA launchers. On the  $V_{\rm DD}$  and  $V_{\rm SS}$  supply traces, a 100 pF bypass capacitor filters high frequency noise.

Figure 24 shows the simplified application circuit for the ADRF5019.

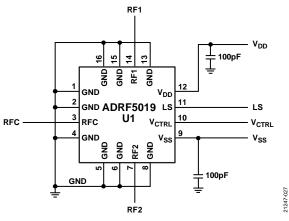
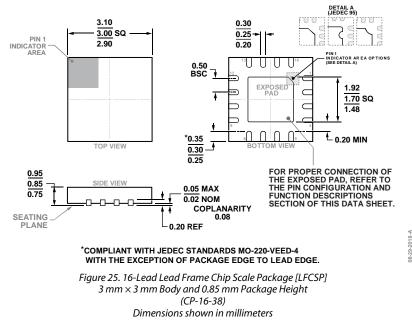


Figure 24. Simplified Application Circuit

# **OUTLINE DIMENSIONS**



### **ORDERING GUIDE**

Model <sup>1</sup>	Temperature Range	Package Description	Package Option	Marking Code
ADRF5019BCPZN	-40°C to +105°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-38	S4Z
ADRF5019BCPZN-R7	-40°C to +105°C	16-Lead Lead Frame Chip Scale Package [LFCSP]	CP-16-38	S4Z
ADRF5019-EVALZ		Evaluation Board		

 $^{1}$  Z = RoHS Compliant Part.

©2019 Analog Devices, Inc. All rights reserved. Trademarks and registered trademarks are the property of their respective owners. D21247-0-8/19(0)



www.analog.com

Rev. 0 | Page 12 of 12

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF Switch ICs category:

Click to view products by Analog Devices manufacturer:

Other Similar products are found below :

MASW-008853-TR3000 BGS13SN8E6327XTSA1 BGSX210MA18E6327XTSA1 SKY13446-374LF SW-227-PIN CG2185X2 CG2415M6 MA4SW410B-1 MASW-002102-13580G MASW-008543-001SMB MASW-008955-TR3000 TGS4307 BGS 12PL6 E6327 BGS1414MN20E6327XTSA1 BGS1515MN20E6327XTSA1 BGSA11GN10E6327XTSA1 BGSX28MA18E6327XTSA1 HMC199AMS8 SKY13374-397LF SKY13453-385LF CG2415M6-C2 HMC986A-SX AS222-92LF SW-314-PIN UPG2162T5N-E2-A SKY13416-485LF MASWSS0204TR-3000 MASWSS0201TR MASWSS0181TR-3000 MASW-007588-TR3000 MASW-004103-13655P MASW-003102-13590G MASWSS0202TR-3000 MA4SW310B-1 MA4SW110 SW-313-PIN CG2430X1 SKY13321-360LF SKY13405-490LF SKYA21001 BGSF 18DM20 E6327 SKY13415-485LF MMS008PP3 BGS13PN10E6327XTSA1 SKY13319-374LF BGS14PN10E6327XTSA1 SKY12213-478LF SKY13404-466LF MASW-011060-TR0500 SKYA21024